



Dioda Zenera BZX85 C6V8;1.3W;DO-41; MIC;Pbf



Dane techniczne:

Nazwa: BZX85

Typ: dioda Zenera

Napięcie: 6.8V

Moc: 1.3W

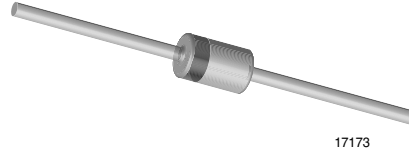
Obudowa: DO-41

Diody Zenera to diody stabilizacyjne, stosowane są do przesuwania poziomów napięć, a także jako element pełniący funkcję zabezpieczenia i działania przeciw przepięciom.

Zener Diodes

Features

- Silicon Planar Power Zener Diodes
- For use in stabilizing and clipping circuits with high power rating
- The Zener voltages are graded according to the international E 24 standard. Replace suffix "C" with "B" for $\pm 2\%$ tolerance
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Applications

- Voltage stabilization

Mechanical Data

Case: DO41 Glass case

Weight: approx. 310 mg

Cathode Band Color: black

Packaging Codes/Options:

TR/5 k per 13" reel (52 mm tape), 25 k/box

TAP/5 k per ammo pack (52 mm tape), 25 k/box

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

| Parameter | Test condition | Symbol | Value | Unit |
|---|----------------|-----------|-------------------|------|
| Zener current (see Table "Electrical Characteristics") | | | | |
| Power dissipation | | P_{tot} | 1.3 ¹⁾ | W |

¹⁾ Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

| Parameter | Test condition | Symbol | Value | Unit |
|--|----------------|------------|-------------------|--------------------|
| Thermal resistance junction to ambient air | | R_{thJA} | 110 ¹⁾ | K/W |
| Junction temperature | | T_j | 175 | $^{\circ}\text{C}$ |
| Storage temperature | | T_{stg} | - 55 to + 175 | $^{\circ}\text{C}$ |

¹⁾ Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature

Electrical Characteristics

| Partnumber | Zener Voltage Range ¹⁾ | | Dynamic Resistance | | | | Temperature Coefficient of Zener Voltage | | Reverse Leakage Current | | Admissible Zener Current ²⁾ |
|------------|-----------------------------------|------|--------------------|-------------|---------------|-------------|--|--------|-------------------------|----------|--|
| | | | $r_{ZT}^{3)}$ | at I_{ZT} | $r_{ZK}^{3)}$ | at I_{ZK} | α_{VZ} at $I_Z = I_{ZT}$ | | at I_R | at V_R | |
| | min | max | Ω | mA | Ω | mA | %/°C | | μA | V | mA |
| BZX85C2V7 | 2.5 | 2.9 | < 20 | 80 | < 400 | 1 | - 0.08 | - 0.05 | < 150 | 1 | 360 |
| BZX85C3V0 | 2.8 | 3.2 | < 20 | 80 | < 400 | 1 | - 0.08 | - 0.05 | < 100 | 1 | 330 |
| BZX85C3V3 | 3.1 | 3.5 | < 20 | 80 | < 400 | 1 | - 0.08 | - 0.05 | < 40 | 1 | 300 |
| BZX85C3V6 | 3.4 | 3.8 | < 20 | 60 | < 500 | 1 | - 0.08 | - 0.05 | < 20 | 1 | 290 |
| BZX85C3V9 | 3.7 | 4.1 | < 15 | 60 | < 500 | 1 | - 0.07 | - 0.02 | < 10 | 1 | 280 |
| BZX85C4V3 | 4 | 4.6 | < 13 | 50 | < 500 | 1 | - 0.05 | 0.01 | < 3 | 1 | 250 |
| BZX85C4V7 | 4.4 | 5 | < 13 | 45 | < 600 | 1 | - 0.03 | 0.04 | < 3 | 1 | 215 |
| BZX85C5V1 | 4.8 | 5.4 | < 10 | 45 | < 500 | 1 | - 0.01 | 0.04 | < 1 | 1.5 | 200 |
| BZX85C5V6 | 5.2 | 6 | < 7 | 45 | < 400 | 1 | 0 | 0.045 | < 1 | 2 | 190 |
| BZX85C6V2 | 5.8 | 6.6 | < 4 | 35 | < 300 | 1 | 0.01 | 0.055 | < 1 | 3 | 170 |
| BZX85C6V8 | 6.4 | 7.2 | < 3.5 | 35 | < 300 | 1 | 0.015 | 0.06 | < 1 | 4 | 155 |
| BZX85C7V5 | 7 | 7.9 | < 3 | 35 | < 200 | 0.5 | 0.02 | 0.065 | < 1 | 4.5 | 140 |
| BZX85C8V2 | 7.7 | 8.7 | < 5 | 25 | < 200 | 0.5 | 0.03 | 0.07 | < 1 | 6.2 | 130 |
| BZX85C9V1 | 8.5 | 9.6 | < 5 | 25 | < 200 | 0.5 | 0.035 | 0.075 | < 1 | 6.8 | 120 |
| BZX85C10 | 9.4 | 10.6 | < 7 | 25 | < 200 | 0.5 | 0.04 | 0.08 | < 0.5 | 7.5 | 105 |
| BZX85C11 | 10.4 | 11.6 | < 8 | 20 | < 300 | 0.5 | 0.045 | 0.08 | < 0.5 | 8.2 | 97 |
| BZX85C12 | 11.4 | 12.7 | < 9 | 20 | < 350 | 0.5 | 0.045 | 0.085 | < 0.5 | 9.1 | 88 |
| BZX85C13 | 12.4 | 14.1 | < 10 | 20 | < 400 | 0.5 | 0.05 | 0.085 | < 0.5 | 10 | 79 |
| BZX85C15 | 13.8 | 15.6 | < 15 | 15 | < 500 | 0.5 | 0.055 | 0.09 | < 0.5 | 11 | 71 |
| BZX85C16 | 15.3 | 17.1 | < 15 | 15 | < 500 | 0.5 | 0.055 | 0.09 | < 0.5 | 12 | 66 |
| BZX85C18 | 16.8 | 19.1 | < 20 | 15 | < 500 | 0.5 | 0.06 | 0.09 | < 0.5 | 13 | 62 |
| BZX85C20 | 18.8 | 21.2 | < 24 | 10 | < 600 | 0.5 | 0.06 | 0.09 | < 0.5 | 15 | 56 |
| BZX85C22 | 20.8 | 23.3 | < 25 | 10 | < 600 | 0.5 | 0.06 | 0.095 | < 0.5 | 16 | 52 |
| BZX85C24 | 22.8 | 25.6 | < 25 | 10 | < 600 | 0.5 | 0.06 | 0.095 | < 0.5 | 18 | 47 |
| BZX85C27 | 25.1 | 28.9 | < 30 | 8 | < 750 | 0.25 | 0.06 | 0.095 | < 0.5 | 20 | 41 |
| BZX85C30 | 28 | 32 | < 30 | 8 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 22 | 36 |
| BZX85C33 | 31 | 35 | < 35 | 8 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 24 | 33 |
| BZX85C36 | 34 | 38 | < 40 | 8 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 27 | 30 |
| BZX85C39 | 37 | 41 | < 50 | 6 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 30 | 28 |
| BZX85C43 | 40 | 46 | < 50 | 6 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 33 | 26 |
| BZX85C47 | 44 | 50 | < 90 | 4 | < 1500 | 0.25 | 0.06 | 0.095 | < 0.5 | 36 | 23 |
| BZX85C51 | 48 | 54 | < 115 | 4 | < 1500 | 0.25 | 0.06 | 0.095 | < 0.5 | 39 | 21 |
| BZX85C56 | 52 | 60 | < 120 | 4 | < 2000 | 0.25 | 0.06 | 0.095 | < 0.5 | 43 | 19 |
| BZX85C62 | 58 | 66 | < 125 | 4 | < 2000 | 0.25 | 0.06 | 0.095 | < 0.5 | 47 | 16 |
| BZX85C68 | 64 | 72 | < 130 | 4 | < 2000 | 0.25 | 0.055 | 0.095 | < 0.5 | 51 | 15 |
| BZX85C75 | 70 | 80 | < 135 | 4 | < 2000 | 0.25 | 0.055 | 0.095 | < 0.5 | 56 | 14 |
| BZX85C82 | 77 | 87 | < 200 | 2.7 | < 3000 | 0.25 | 0.055 | 0.095 | < 0.5 | 62 | 12 |
| BZX85C91 | 85 | 96 | < 250 | 2.7 | < 3000 | 0.25 | 0.055 | 0.095 | < 0.5 | 68 | 10 |
| BZX85C100 | 96 | 106 | < 350 | 2.7 | < 3000 | 0.25 | 0.055 | 0.095 | < 0.5 | 75 | 9.4 |

¹⁾ Measured with pulses $t_p = 5$ ms

²⁾ Valid provided that leads are kept at ambient temperature at a distance of 10 mm from case

³⁾ Measured with $f = 1$ kHz



Electrical Characteristics

| Partnumber | Zener Voltage Range ¹⁾ | | Dynamic Resistance | | | | Temperature Coefficient of Zener Voltage | | Reverse Leakage Current | | Admissible Zener Current ²⁾ |
|------------|-----------------------------------|------|-------------------------------|--------------------|-------------------------------|--------------------|---|--------|-------------------------|-------------------|--|
| | V _Z at I _{ZT} | | r _{ZT} ³⁾ | at I _{ZT} | r _{ZK} ³⁾ | at I _{ZK} | α _{VZ} at I _Z = I _{ZT} | | at I _R | at V _R | I _Z |
| | V | | Ω | mA | Ω | mA | %/°C | | μA | V | mA |
| | min | max | | | | | min | max | | | |
| BZX85B2V7 | 2.64 | 2.76 | < 20 | 80 | < 400 | 1 | - 0.08 | - 0.05 | < 150 | 1 | 360 |
| BZX85B3V0 | 2.94 | 3.06 | < 20 | 80 | < 400 | 1 | - 0.08 | - 0.05 | < 100 | 1 | 330 |
| BZX85B3V3 | 2.24 | 3.36 | < 20 | 80 | < 400 | 1 | - 0.08 | - 0.05 | < 40 | 1 | 300 |
| BZX85B3V6 | 3.53 | 3.67 | < 20 | 60 | < 500 | 1 | - 0.08 | - 0.05 | < 20 | 1 | 290 |
| BZX85B3V9 | 3.82 | 3.98 | < 15 | 60 | < 500 | 1 | - 0.07 | - 0.02 | < 10 | 1 | 280 |
| BZX85B4V3 | 4.21 | 4.39 | < 13 | 50 | < 500 | 1 | - 0.05 | 0.01 | < 3 | 1 | 250 |
| BZX85B4V7 | 4.61 | 4.79 | < 13 | 45 | < 600 | 1 | - 0.03 | 0.04 | < 3 | 1 | 215 |
| BZX85B5V1 | 5 | 5.2 | < 10 | 45 | < 500 | 1 | - 0.01 | 0.04 | < 1 | 1.5 | 200 |
| BZX85B5V6 | 5.49 | 5.71 | < 7 | 45 | < 400 | 1 | 0 | 0.045 | < 1 | 2 | 190 |
| BZX85B6V2 | 6.08 | 6.32 | < 4 | 35 | < 300 | 1 | 0.01 | 0.055 | < 1 | 3 | 170 |
| BZX85B6V8 | 6.66 | 6.94 | < 3.5 | 35 | < 300 | 1 | 0.015 | 0.06 | < 1 | 4 | 155 |
| BZX85B7V5 | 7.35 | 7.65 | < 3 | 35 | < 200 | 0.5 | 0.02 | 0.065 | < 1 | 4.5 | 140 |
| BZX85B8V2 | 8.04 | 8.36 | < 5 | 25 | < 200 | 0.5 | 0.03 | 0.07 | < 1 | 6.2 | 130 |
| BZX85B9V1 | 8.92 | 9.28 | < 5 | 25 | < 200 | 0.5 | 0.035 | 0.075 | < 1 | 6.8 | 120 |
| BZX85B10 | 9.8 | 10.2 | < 7 | 25 | < 200 | 0.5 | 0.04 | 0.08 | < 0.5 | 7.5 | 105 |
| BZX85B11 | 10.8 | 11.2 | < 8 | 20 | < 300 | 0.5 | 0.045 | 0.08 | < 0.5 | 8.2 | 97 |
| BZX85B12 | 11.8 | 12.2 | < 9 | 20 | < 350 | 0.5 | 0.045 | 0.085 | < 0.5 | 9.1 | 88 |
| BZX85B13 | 12.7 | 13.3 | < 10 | 20 | < 400 | 0.5 | 0.05 | 0.085 | < 0.5 | 10 | 79 |
| BZX85B15 | 14.7 | 15.3 | < 15 | 15 | < 500 | 0.5 | 0.055 | 0.09 | < 0.5 | 11 | 71 |
| BZX85B16 | 15.7 | 16.3 | < 15 | 15 | < 500 | 0.5 | 0.055 | 0.09 | < 0.5 | 12 | 66 |
| BZX85B18 | 17.6 | 18.4 | < 20 | 15 | < 500 | 0.5 | 0.06 | 0.09 | < 0.5 | 13 | 62 |
| BZX85B20 | 19.6 | 20.4 | < 24 | 10 | < 600 | 0.5 | 0.06 | 0.09 | < 0.5 | 15 | 56 |
| BZX85B22 | 21.6 | 22.4 | < 25 | 10 | < 600 | 0.5 | 0.06 | 0.095 | < 0.5 | 16 | 52 |
| BZX85B24 | 23.5 | 24.5 | < 25 | 10 | < 600 | 0.5 | 0.06 | 0.095 | < 0.5 | 18 | 47 |
| BZX85B27 | 26.5 | 27.5 | < 30 | 8 | < 750 | 0.25 | 0.06 | 0.095 | < 0.5 | 20 | 41 |
| BZX85B30 | 29.4 | 30.6 | < 30 | 8 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 22 | 36 |
| BZX85B33 | 32.3 | 33.7 | < 35 | 8 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 24 | 33 |
| BZX85B36 | 35.3 | 36.7 | < 40 | 8 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 27 | 30 |
| BZX85B39 | 38.2 | 39.8 | < 50 | 6 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 30 | 28 |
| BZX85B43 | 42.1 | 43.9 | < 50 | 6 | < 1000 | 0.25 | 0.06 | 0.095 | < 0.5 | 33 | 26 |
| BZX85B47 | 46.1 | 47.9 | < 90 | 4 | < 1500 | 0.25 | 0.06 | 0.095 | < 0.5 | 36 | 23 |
| BZX85B51 | 50 | 52 | < 115 | 4 | < 1500 | 0.25 | 0.06 | 0.095 | < 0.5 | 39 | 21 |
| BZX85B56 | 54.9 | 57.1 | < 120 | 4 | < 2000 | 0.25 | 0.06 | 0.095 | < 0.5 | 43 | 19 |
| BZX85B62 | 60.8 | 63.2 | < 125 | 4 | < 2000 | 0.25 | 0.06 | 0.095 | < 0.5 | 47 | 16 |
| BZX85B68 | 66.6 | 69.4 | < 130 | 4 | < 2000 | 0.25 | 0.055 | 0.095 | < 0.5 | 51 | 15 |
| BZX85B75 | 73.5 | 76.5 | < 135 | 4 | < 2000 | 0.25 | 0.055 | 0.095 | < 0.5 | 56 | 14 |
| BZX85B82 | 80.4 | 83.6 | < 200 | 2.7 | < 3000 | 0.25 | 0.055 | 0.095 | < 0.5 | 62 | 12 |
| BZX85B91 | 89.2 | 92.8 | < 250 | 2.7 | < 3000 | 0.25 | 0.055 | 0.095 | < 0.5 | 68 | 10 |
| BZX85B100 | 98 | 102 | < 350 | 2.7 | < 3000 | 0.25 | 0.055 | 0.095 | < 0.5 | 75 | 9.4 |

¹⁾ Measured with pulses t_p = 5 ms

²⁾ Valid provided that leads are kept at ambient temperature at a distance of 10 mm from case

³⁾ Measured with f = 1 kHz

Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

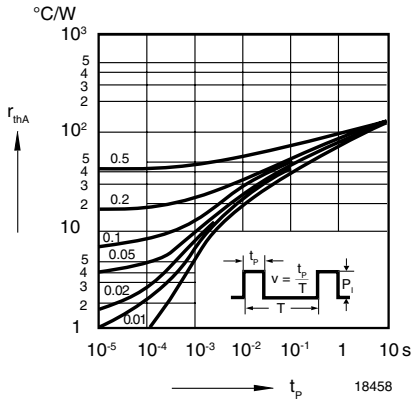


Figure 1. Pulse Thermal Resistance vs. Pulse Duration

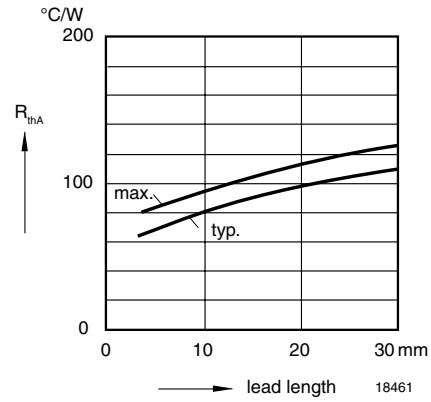


Figure 4. Thermal Resistance vs. Lead Length

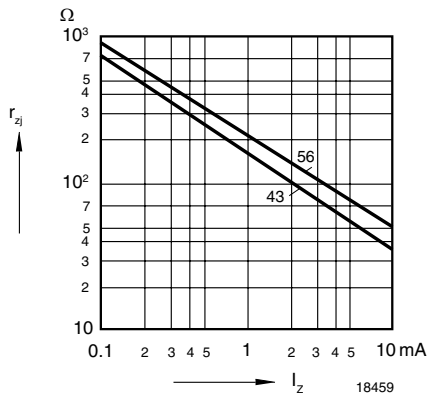


Figure 2. Dynamic Resistance vs. Zener Current

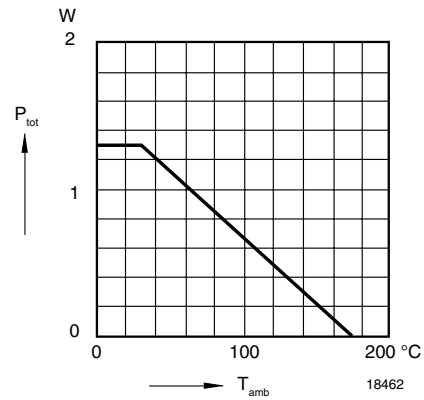


Figure 5. Admissible Power Dissipation vs. Ambient Temperature

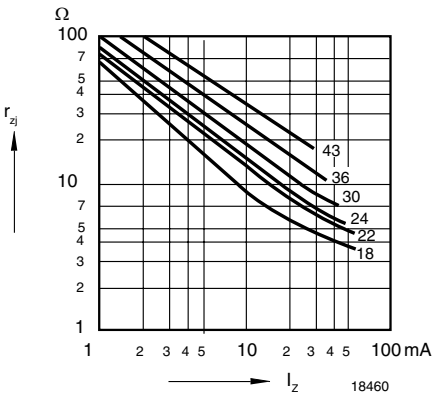


Figure 3. Dynamic Resistance vs. Zener Current

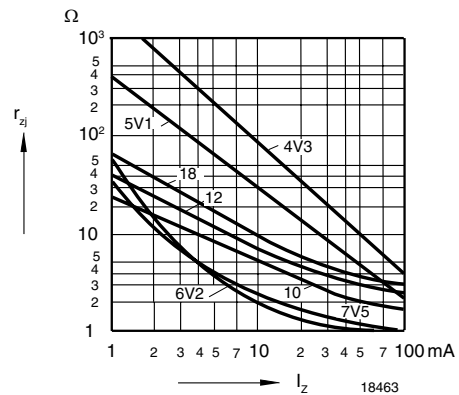


Figure 6. Dynamic Resistance vs. Zener Current

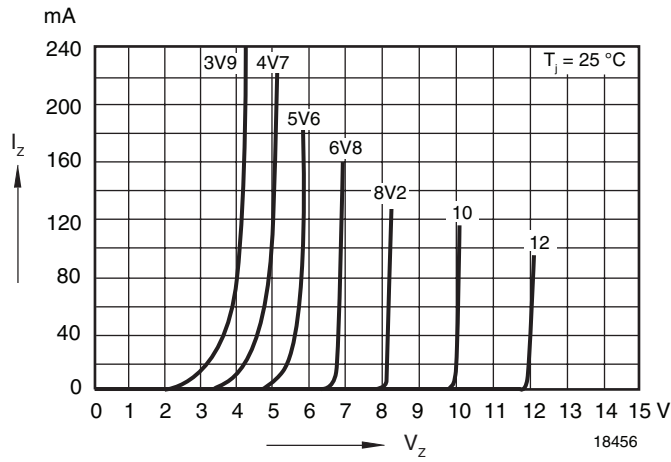


Figure 7. Breakdown Characteristics

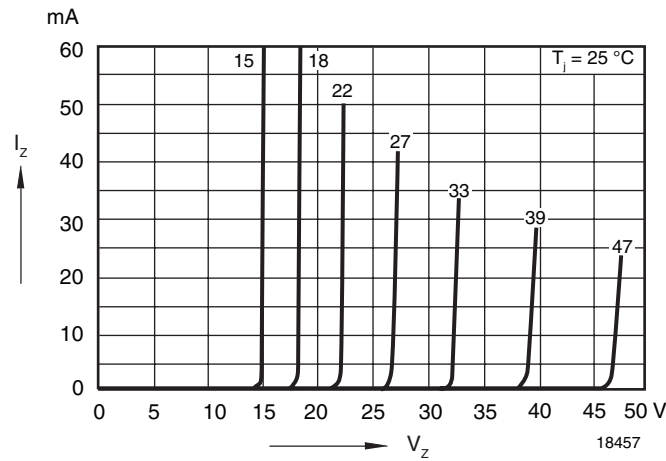
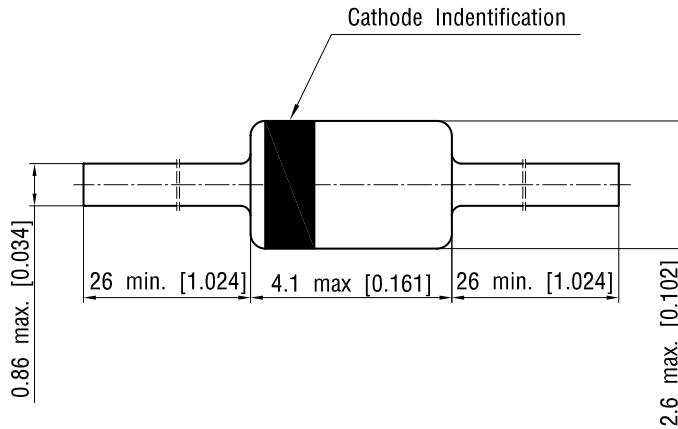


Figure 8. Breakdown Characteristics

Package Dimensions in millimeters (inches)



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 94 9368

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
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